

L Number	Hits	Search Text	DB	Time stamp
271	2	("3970887").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/15 22:15
-	165	cathey near david	USPAT; DERWENT	2004/04/13 17:17
-	121	(cathey near david) and emitter	USPAT; DERWENT	2003/04/13 15:10
-	11	(cathey near david) and emitter and impurity	USPAT; DERWENT	2003/04/13 15:10
-	2	("5532177").PN.	USPAT; DERWENT	2003/04/15 10:02
-	2	("5372973").PN.	USPAT; DERWENT	2003/04/15 11:37
-	3	("8609354").PN.	USPAT; DERWENT	2003/04/25 10:44
-	2	("4940916").PN.	USPAT; DERWENT	2003/04/25 10:27
-	2	("5528103").PN.	USPAT; DERWENT	2003/04/25 10:27
-	2	("5550435").PN.	USPAT; DERWENT	2003/04/25 10:47
-	2	("5559389").PN.	USPAT; DERWENT	2003/04/25 10:48
-	2	("5789857").PN.	USPAT; DERWENT	2003/04/25 10:48
-	2	("5269877").PN.	USPAT; DERWENT	2003/09/30 14:11
-	2	("5703380").PN.	USPAT; DERWENT	2003/09/30 16:04
-	2	("5552613").PN.	USPAT; DERWENT	2004/01/22 15:14
-	2	("5703380").PN.	USPAT; DERWENT	2004/01/22 15:14
-	2	("6031250").PN.	USPAT; DERWENT	2004/01/22 15:46
-	2	("5269877").PN.	USPAT; DERWENT	2004/01/22 16:06

	2	("4400866").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/01/22 16:07
	52	313/336,309,495,308.ccls. and emitter and substrate and (impurity or dopant or doping or doped) and decrease and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	60	313/336,309,351.ccls. and ((impurity or dopant or doping or doped) with (boron or arsenic or phosphor or phosphorous or phosphorus)) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	22	313/336,309,495,308.ccls. and emitter and substrate and impurity and decrease and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	215	313/336,309,351.ccls. and (emitter or tip or base or apex) and (impurity or dopant or doping or doped) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	82	313/336,309,495,308.ccls. and emitter and (impurity or dopant or doping or doped) and (decrease or gradient) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	66	313/336,309,495,308.ccls. and emitter and (impurity or dopant or doping or doped) and decrease and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	266	313/336,495.ccls. and emitter and (dopant or impurit\$3)	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	21	313/336,309,495,308.ccls. and emitter and ((impurity or dopant or doping or doped) with (boron or arsenic or phosphor or phosphorous)) and (decrease or gradient) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/04/15 17:28
	44	313/336,309,495,308.ccls. and substrate and impurity with emitter	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	23	313/336,309,495,308.ccls. and emitter and ((impurity or dopant or doping or doped) with (boron or arsenic or phosphor or phosphorous or phosphorus)) and (decrease or gradient) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	360	313/336,495.ccls. and emitter and decrease	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	177	313/336,309,351.ccls. and emitter and (impurity or dopant or doping or doped) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	53	313/336,309,351.ccls. and emitter and ((impurity or dopant or doping or doped) with (boron or arsenic or phosphor or phosphorous or phosphorus)) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	221	313/336,309,351.ccls. and (impurity or dopant or doping or doped) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	2	313/336,495.ccls. and emitter and (dopant or impurit\$3) with decrease	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	496	313/336,495.ccls. and emitter and (dop\$3 or impurit\$3)	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	1748	313/336,495.ccls.	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	100	313/336,309,495,308.ccls. and emitter and substrate and impurity and decrease	USPAT; US-PGPUB; DERWENT	2004/02/04 11:26
	2	("6091188").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/02/04 11:35

-	2	("6031250").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/13 17:26
-	2	("5269877").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/13 17:30
-	214	313/\$3.ccls. and @ad<19930707 and substrate with (semiconduct\$3 and silicon)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/13 17:32
-	214	313/\$3.ccls. and @ad<19930707 and (substrate with (semiconduct\$3 and silicon))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/13 18:03
-	2	("5269877").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/13 18:03
-	216	313/336,309,495,308,351.ccls. and emitter and (impurity or dopant or doping or doped) and @ad<19960301	USPAT; US-PGPUB; DERWENT	2004/04/15 21:29
-	2	("5269877").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/04/15 17:57
-	90	313/336,309,495,308,351.ccls. and emitter and (impurity or dopant or doping or doped) and @ad<19930707	USPAT; US-PGPUB; DERWENT	2004/04/15 22:15